

CSM212P3S323

20V P-Channel Enhancement Mode MOSFET

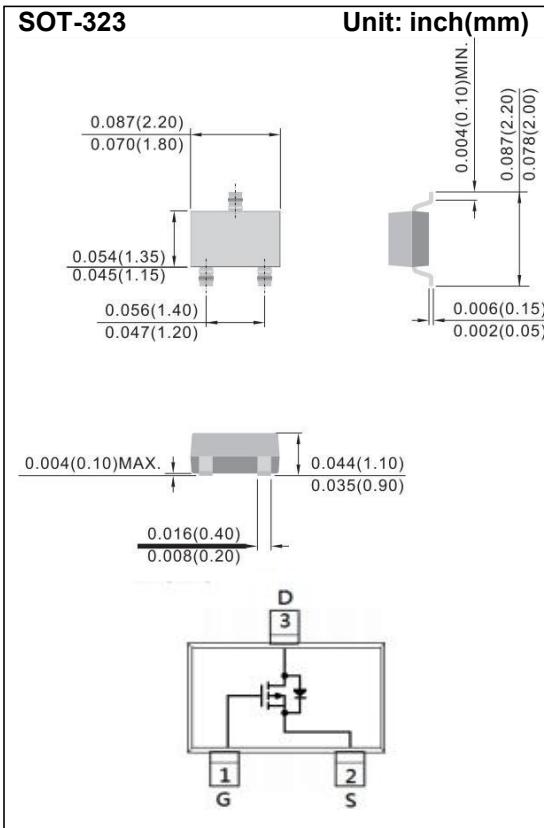
Voltage -20 V Current -3A

Features

- R_{DS(ON)}, V_{GS}@-4.5V, I_D@-3.1A<100mΩ
- R_{DS(ON)}, V_{GS}@-2.5V, I_D@-2.0A<135mΩ
- R_{DS(ON)}, V_{GS}@-1.8V, I_D@-1.1A<190mΩ
- Advanced Trench Process Technology

Mechanical Data

- Case: SOT-323 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.00018 ounces, 0.005 grams



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V _{DS}	-20	V
Gate-Source Voltage	V _{GS}	± 12	V
Continuous Drain Current	I _D	-3	A
Pulsed Drain Current	I _{DM}	-12.5	A
Power Dissipation	P _D	1.25	W
		10	mW/°C
Operating Junction and Storage Temperature Range	T _J , T _{STG}	-55~150	°C
Typical Thermal Resistance - Junction to Ambient (Note 3)	R _{θJA}	100	°C/W

CSM212P3S323

Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=-250\mu\text{A}$	-20	-	-	V
Gate Threshold Voltage	$V_{\text{GS(th)}}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=-250\mu\text{A}$	-0.4	-0.71	-1.2	V
Drain-Source On-State Resistance	$R_{\text{DS(on)}}$	$V_{\text{GS}}=-4.5\text{V}, I_{\text{D}}=-3.1\text{A}$	-	84	100	$\text{m}\Omega$
		$V_{\text{GS}}=-2.5\text{V}, I_{\text{D}}=-2.0\text{A}$	-	104	135	
		$V_{\text{GS}}=-1.8\text{V}, I_{\text{D}}=-1.1\text{A}$	-	134	190	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}}=-20\text{V}, V_{\text{GS}}=0\text{V}$	-	-0.01	-1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{\text{GS}}=\pm 12\text{V}, V_{\text{DS}}=0\text{V}$	-	± 10	± 100	nA
Dynamic						
Total Gate Charge	Q_g	$V_{\text{DS}}=-10\text{V}, I_{\text{D}}=-3.1\text{A}, V_{\text{GS}}=-4.5\text{V}$ <small>(Note 1,2)</small>	-	5.4	-	nC
Gate-Source Charge	Q_{gs}		-	0.7	-	
Gate-Drain Charge	Q_{gd}		-	1.3	-	
Input Capacitance	C_{iss}	$V_{\text{DS}}=-10\text{V}, V_{\text{GS}}=0\text{V}, f=1.0\text{MHz}$	-	416	-	pF
Output Capacitance	C_{oss}		-	43	-	
Reverse Transfer Capacitance	C_{rss}		-	32	-	
Switching						
Turn-On Delay Time	$t_{\text{d(on)}}$	$V_{\text{DD}}=-10\text{V}, I_{\text{D}}=-3.1\text{A}, V_{\text{GS}}=-4.5\text{V}, R_{\text{G}}=6\Omega$ <small>(Note 1,2)</small>	-	4	-	ns
Turn-On Rise Time	t_{r}		-	27	-	
Turn-Off Delay Time	$t_{\text{d(off)}}$		-	78	-	
Turn-Off Fall Time	t_{f}		-	45	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_{s}	---	-	-	-1.5	A
Diode Forward Voltage	V_{SD}	$I_{\text{s}}=-1.0\text{A}, V_{\text{GS}}=0\text{V}$	-	0.8	-1.2	V

NOTES :

1. Pulse width $\leq 300\text{us}$, Duty cycle $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
4. The maximum current rating is package limited

CSM212P3S323

TYPICAL CHARACTERISTIC CURVES

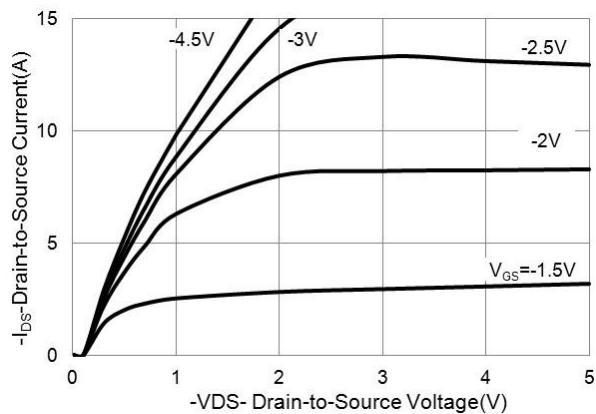


Fig.1 On-Region Characteristics

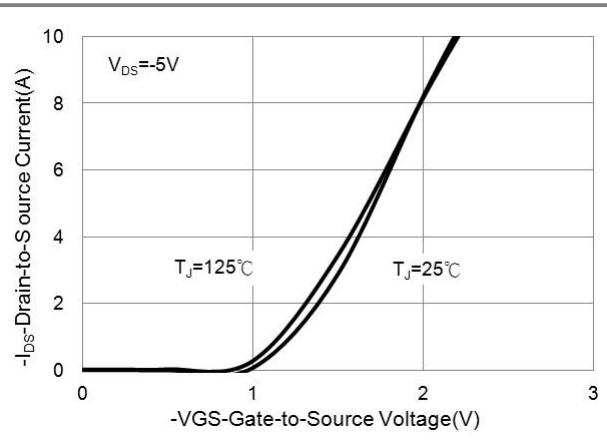


Fig.2 Transfer Characteristics

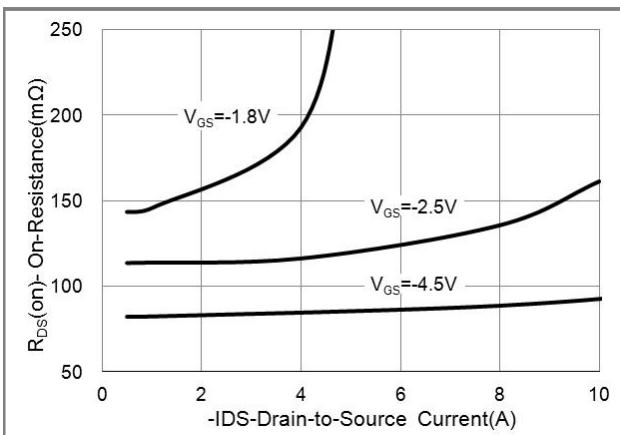


Fig.3 On-Resistance vs. Drain Current

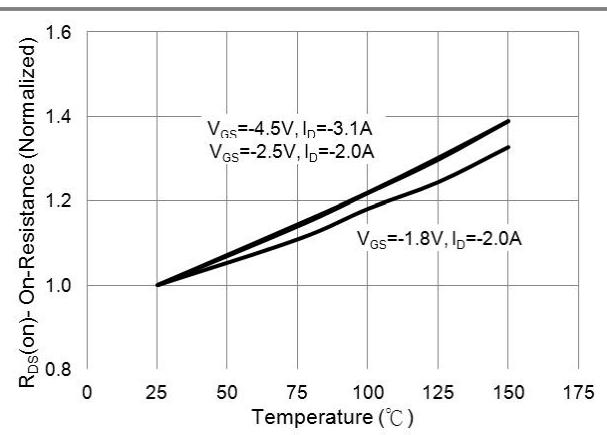


Fig.4 On-Resistance vs. Junction temperature

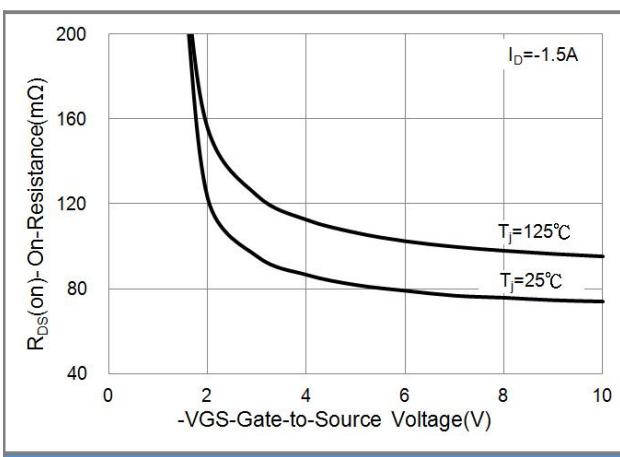


Fig.5 On-Resistance Variation with VGS.

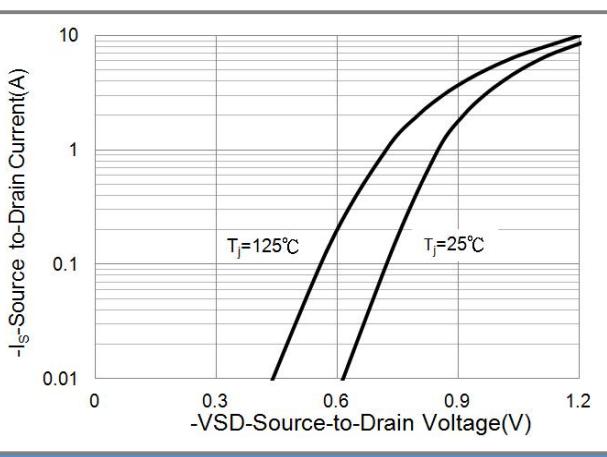


Fig.6 Body Diode Characteristics

CSM212P3S323

TYPICAL CHARACTERISTIC CURVES

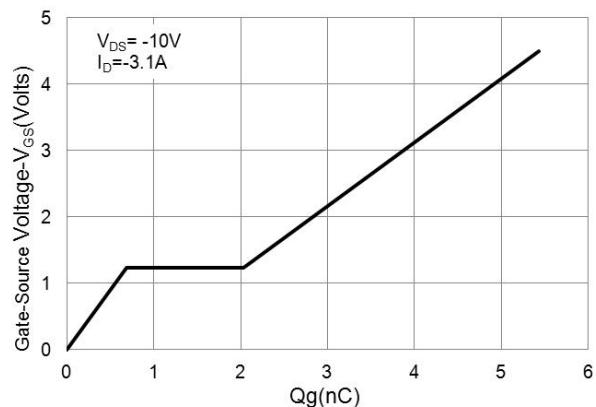


Fig.7 Gate-Charge Characteristics

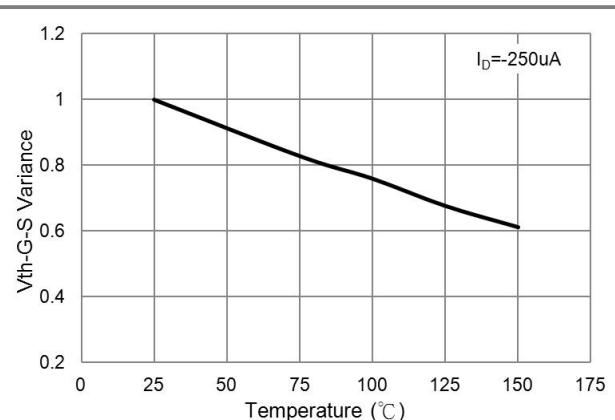


Fig.8 Threshold Voltage Variation with Temperature.

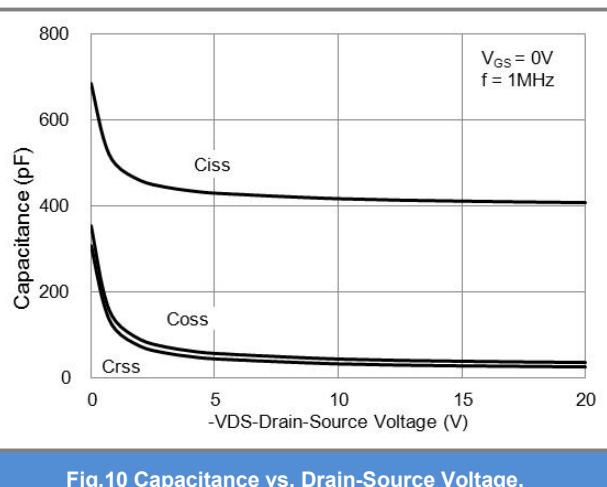


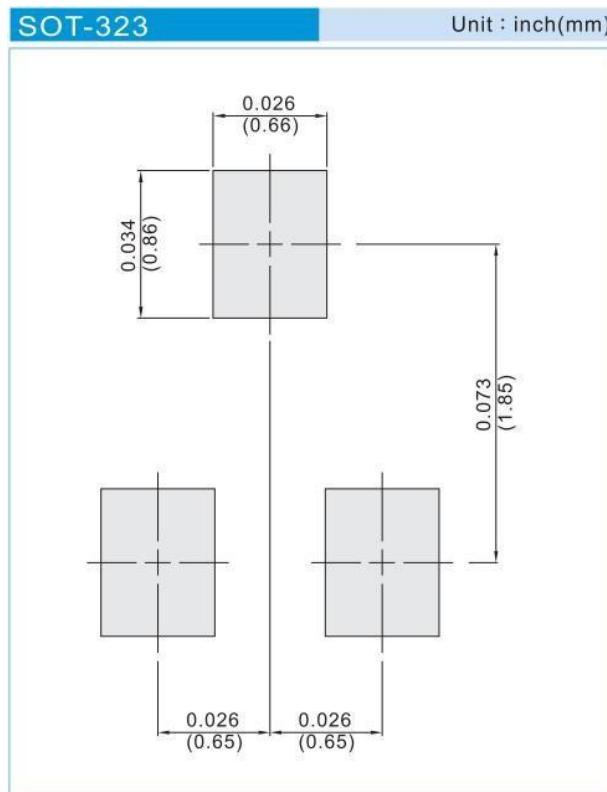
Fig.10 Capacitance vs. Drain-Source Voltage.

CSM212P3S323

PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type
CSM212P3S323	SOT-323	3K pcs / 7" reel

MOUNTING PAD LAYOUT



CSM212P3S323

Notice

Specifications of the products displayed herein are subject to change without notice. CCS or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in CCS terms and conditions of sale for such products, CCS assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of CCS products including liability or warranties relating to fitness for a particular purpose, merchant ability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications.

Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify CCS for any damages resulting from such improper use or sale.